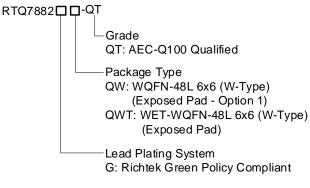
# USB Type-C PD and PWM Buck-Boost Controller with AnyPower<sup>™</sup> and PD Safe<sup>®</sup> Features

### **General Description**

The RTQ7882-QT is a USB Type-C Power Delivery (USBC PD) and PWM buck-boost controller with highly integrated functions and flexibility for USB PD provider applications. The IC has an embedded ARM Cortex<sup>TM</sup>-M0 MCU, which handles various functions of communication protocol, smart control of the PWM converter, firmware-based protections, and customized functions. The IC features hardware-based protections, such as inductor peak current limit, VBUS overvoltage protection (VBUS OVP), VIN undervoltage protection (VIN UVP), VIN overvoltage protection (VIN OVP), VO undervoltage protection (VO UVP), and VCONN current-limit protection, so that the protections have faster responses and can still function even when the MCU is not activated. The RTQ7882-QT can offer an excellent USB PD solution for a USB-PD Provider application with few external components and simple PCB layout.

### **Ordering Information**



Note:

Richtek products are Richtek Green Policy compliant and compatible with the current requirements of IPC/JEDEC J-STD-020.

### Applications

Automotive USB Type-C Power Delivery Charger

### Features

- Support USB Type-C Power Delivery (PD) Provider
- AEC-Q100 Grade 2 Qualified
- Operating Ambient Temperature: -40°C to 105°C
- Type-C, USB PD and Communication Protocols
  - Compliant with USB PD 3.1 Specification, USB
     Type-C Cable and Connector Specification 2.1
  - VCONN Output 100mW
  - Support Other Proprietary Communication Protocols through Internal MCU, DP and DM Pins
- Integrated PWM Buck-Boost Controller
  - ▶ Wide Input Voltage Range: 4.5V to 30V
  - ► Wide Output Voltage Range: 3.3V to 21V
  - Peak-Current Mode PWM Operation
  - Internal Compensation for CV, CC
  - Programmable PWM Switching Frequency (200kHz to 600kHz)
  - Pulse-Skipping Mode for Light-Load Efficiency; Selectable Forced CCM Operation
- AnyPower<sup>TM</sup> for Constant Voltage Output and Constant Current Output
- PD Safe<sup>®</sup>
  - Adjustable Converter Input Overcurrent Limit (INOC)
  - ► Fast Response VIN OVP/UVP Detection
  - Programmable VBUS OVP and VO UVP
  - ► Fast Response OVP for CC1/2 and D+/D-
  - Adjustable External OTP/Internal OTP
  - CC1/2 Output Current Limit
  - CC1/2, D+/D- 25V Tolerant
- Cable Voltage Drop Compensation for VBUS
- Switching Frequency Synchronization for Better EMI
- Adjustable Gate Drive Current for Better EMI
- Firmware-based Functions
   VIN De-Rating and Power Sharing
- Master and Slave I<sup>2</sup>C Interfaces, LED Drivers, GPIOs



- Built-in Output Bleeders for Quick VBUS
  Discharge
- Built-in Charge Pump for Driving Cost-Effective N-MOSFETs
- Built-in Internal LDO
- Online Firmware Update via Slave I<sup>2</sup>C Interface or CC1/2 Interface
- Available in WQFN-48L or WET-WQFN-48L 6x6 Package
- USB PD PD3.1/PPS Certification Passed (TID 8011)

### **Marking Information**

#### RTQ7882GQWT-QT



RTQ7882GQWT-QT: Product Code YMDNN: Date Code

### RTQ7882GQW-QT



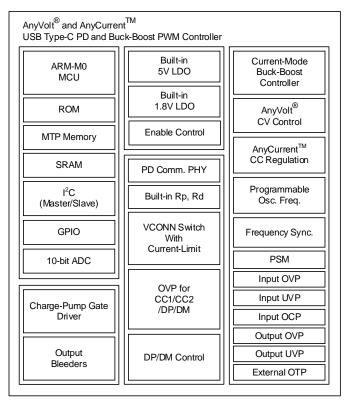
RTQ7882GQW-QT: Product Code YMDNN: Date Code

### **Pin Configuration**

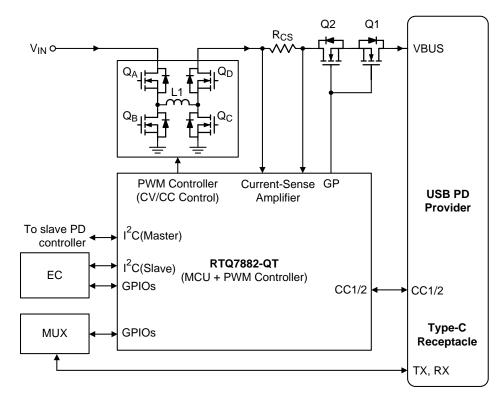
IRQ/ALERT **RQ/ALERT** GND GPIOV SDA2 SCK2 SDA1 SCK1 GPIOI GPIO SΥN RT2 RT1 SCK2 SDA1 SCK1 SDA2 GPIO/ 48 47 46 45 44 43 42 41 40 39 38 37 VBUS GND 36 1 48 47 46 DM 2 35 GP GND VBUS 36 vo DP 34 3 GP DM 35 34 33 32 31 CSON CC2 4 33 DP VO CSOP CC1 32 5 CC2 CSON 4 CCGND 31 BLD CSOP CC1 GND ZCD V2 30 CCGND BLD Exposed Pad ZCD ΕN 29 NC V2 30 8 BOOT2 NC VDD ΕN 28 29 9 VDD BOOT2 GND 10 27 NC 49 28 27 26 25 VIN UGATE2 GND 49 NC 11 26 VIN UGATE2 PCIP/CSIP 12 PHASE2 25 PCIP/CSIP PHASE2 13 14 15 16 20 21 22 23 24 18 19 13 14 15 16 17 18 19 20 21 22 23 24 Ŷ PGND Ŷ S PVDD -GATE2 PCIN BOOT1 PHASE1 SSIN **JGATE1** -GATE1 GATE1 PGND PVDD GATE2 CSIN g BOOT1 g GATE1 PHASE1 g WQFN-48L 6x6 WET-WQFN-48L 6x6

(TOP VIEW)

### Simplified Functional Block Diagram



### **Simplified Application Circuit**





### **Functional Pin Description**

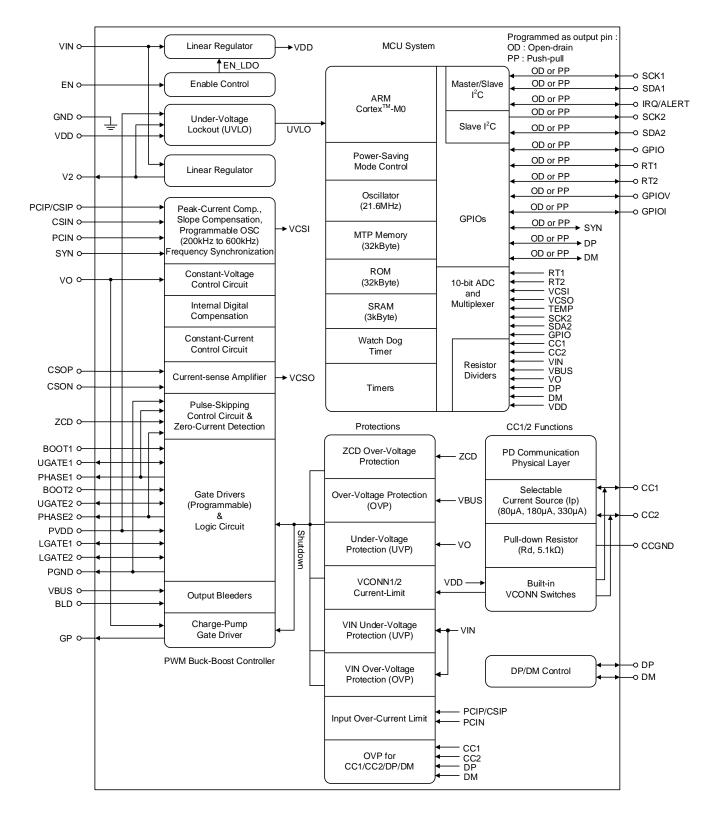
| Pin No.               | Pin Name  | Pin Function  |
|-----------------------|-----------|---|
| 1, 10, 38             | GND       | Analog ground.  |
| 2                     | DM        | Input/Output pin of built-in DPDM interface for BC1.2 and proprietary protocols.<br>Connect this pin to D- pin of a USB connector. This pin can be set as an<br>open-drain or push-pull GPIO pin. |
| 3                     | DP        | Input/Output pin of built-in DPDM interface for BC1.2 and proprietary protocols.<br>Connect this pin to D+ pin of a USB connector. This pin can be set as an<br>open-drain or push-pull GPIO pin. |
| 4                     | CC2       | Type-C connector Configuration Channel (CC) 2. Generally, this input/output pin is connected to USB Type-C connector CC2 terminal.  |
| 5                     | CC1       | Type-C connector Configuration Channel (CC) 1. Generally, this input/output pin is connected to USB Type-C connector CC1 terminal.  |
| 6                     | CCGND     | Ground for Configuration Channel (CC) circuitry.  |
| 7                     | V2        | Internal 1.8V linear regulator output to supply power for internal circuitry. An MLCC (1µF typ. or greater) must be connected from this pin to ground.  |
| 8                     | EN        | Enable control input with internal pull high source. Keep floating for normal operation.  |
| 9                     | VDD       | Output pin of the VIN-to-VDD linear regulator. An external MLCC (at least 4.7 $\mu$ F, 0805/X5R/25V) and a 5.6V zener diode (tolerance 5.6V±2%) must be connected from this pin to GND pin.       |
| 11                    | VIN       | Input voltage to the converter and the IC. An aluminum hybrid polymer capacitor (at least $68\mu$ F) must be connected from converter VIN to ground.  |
| 12                    | PCIP/CSIP | Positive peak-current signal input pin and positive average-current signal input pin.   |
| 13                    | CSIN      | Negative average-current signal input pin.  |
| 14                    | PCIN      | Negative peak-current signal input pin.   |
| 15, 17, 20,<br>27, 29 | NC        | No internal connection.   |
| 16                    | BOOT1     | Bootstrap capacitor connection node. Connect a $0.1\mu$ F ceramic capacitor from this pin and the PHASE1 pin to power the internal $1^{st}$ high-side gate driver.                                |
| 18                    | UGATE1    | 1 <sup>st</sup> High-side gate driver output.   |
| 19                    | PHASE1    | Negative power-rail pin of the 1 <sup>st</sup> high-side gate driver.   |
| 21                    | LGATE1    | 1 <sup>st</sup> Low-side gate driver output.  |
| 22                    | PGND      | Ground of the low-side gate drivers and one input pin of zero-current detection<br>at the MOSFET controlled by LGATE1. Connect this pin to the source of the<br>MOSFET.                           |
| 23                    | PVDD      | Bias voltage (5V typ.) supply for the low-side gate drivers. It is recommended to connect an external MLCC (1 $\mu$ F) from this pin to PGND pin.   |
| 24                    | LGATE2    | 2 <sup>nd</sup> Low-side gate driver output.  |
| 25                    | PHASE2    | Negative power-rail pin of the 2 <sup>nd</sup> high-side gate driver.   |
| 26                    | UGATE2    | 2 <sup>nd</sup> High-side gate driver output.   |
| 28                    | BOOT2     | Bootstrap capacitor connection node. Connect a $0.1\mu$ F ceramic capacitor from this pin and the PHASE2 pin to power the internal 2 <sup>nd</sup> high-side gate driver.                         |

## **RTQ7882-QT**

| Pin No.             | Pin Name  | Pin Function   |
|---------------------|-----------|--|
| 30                  | ZCD       | One input pin of zero-current detection (at the MOSFET controlled by UGATE2) and Output overvoltage protection input pin.  |
| 31                  | BLD       | Bleeder connection node. An output bleeder, comprising a pull-low NMOS, is built in to provide another path to discharge the output capacitor of the PWM converter. Connect this pin to the converter output through an external resistor.   |
| 32                  | CSOP      | Positive input of a current-sense amplifier to sense the output current for constant current regulation and also through an ADC to the MCU. Connect this pin to the positive terminal of output current-sense resistor via an RC filter.   |
| 33                  | CSON      | Negative input of a current-sense amplifier for output constant-current regulation<br>and output current detection. Connect this pin to the negative terminal of output<br>current-sense resistor via an RC filter.  |
| 34                  | VO        | Input of feedback voltage from converter output. The voltage is monitored for output undervoltage protection.  |
| 35                  | GP        | Charge-pump gate diver output. It drives N-channel power MOSFET(s) to turn on/off the output power path.   |
| 36                  | VBUS      | USB-C VBUS voltage input. The voltage at this pin is monitored for USB-C VBUS overvoltage protection with an 8-bit programmable threshold voltage.   |
| 37                  | GPIOV     | General-purpose input/output.  |
| 39                  | GPIOI     | General-purpose input/output.  |
| 40                  | RT2       | Open-drain/push-pull GPIO, analog input or external over-temperature protection (EOTP)input pin. Connect an NTC from this pin to GND pin for the EOTP.   |
| 41                  | RT1       | Open-drain/push-pull GPIO, analog input or external over-temperature protection (EOTP)input pin. Connect an NTC from this pin to GND pin for the EOTP.   |
| 42                  | IRQ/ALERT | Interrupt input/output pin. The RTQ7882-QT can do emergency control when it receives a low-level signal via this pin; an external MCU can check the slave I <sup>2</sup> C registers to do emergency control when it receives a low-level signal via this pin. This pin can be set as an open-drain or push-pull GPIO pin. |
| 43                  | SCK1      | Open-drain clock signal input/output pin of the Slave/Master I <sup>2</sup> C interface. This pin can be set as an open-drain or push-pull GPIO pin.   |
| 44                  | SDA1      | Open-drain data signal input/output pin of the Slave/Master I <sup>2</sup> C interface. This pin can be set as an open-drain or push-pull GPIO pin.  |
| 45                  | SCK2      | Open-drain clock signal input/output pin of the Slave/Master I <sup>2</sup> C interface. This pin can be set as an open-drain or push-pull GPIO pin.   |
| 46                  | SDA2      | Open-drain data signal input/output pin of the Slave/Master I <sup>2</sup> C interface. This pin can be set as an open-drain or push-pull GPIO pin.  |
| 47                  | SYN       | Switching frequency synchronization in two port application.   |
| 48                  | GPIO      | General-purpose input/output.  |
| 49<br>(Exposed Pad) | GND       | Ground. The exposed pad must be soldered to a large PCB and connected to GND for maximum power dissipation.  |



### **Functional Block Diagram**



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### Operation

The RTQ7882-QT is a versatile USB Type-C Power Delivery (USB-C PD) and PWM Buck-Boost controller designed especially for applications as Providers. It is a highly integrated solution, comprising four main functional blocks: MCU System, PWM Buck-Boost Controller, Protections and CC1/2 Functions as depicted in the "Functional Block Diagram".

The MCU System embeds an ARM Cortex<sup>TM</sup>-M0 MCU, a multi-time programming (MTP) memory, a ROM, an SRAM, a 10-bit ADC (analog to digital converter), two I<sup>2</sup>C interfaces (slave and master) and GPIO (general purpose input or output) pins. The MCU System is programmed to perform power controls, customized functions, as a policy engine and a device policy manager. This MCU reports the operating status of PD operation, such as present input/output voltage, output current and external temperature to an EC (embedded controller) or AP (application processor) and receives commands from the EC/AP, as a system policy manager, via the slave I<sup>2</sup>C interface. The GPIO pins can be used to control high-speed multiplexers or other customized functions.

The "PWM Buck-Boost controller" consists of an AnyVolt<sup>®</sup> constant-voltage (CV) control circuit (9.93mV/step, typ.), an AnyCurrent<sup>TM</sup> constant-current (CC) control circuit, an output current-sense amplifier (7.8mA 12.5mA/step, depending to on the current-sense resistor), built-in gate drivers, one charge-pump gate driver and output bleeders (at BLD and VBUS pins). Generally, either the CV or the CC control circuit regulates the output voltage or current through peak-current mode PWM operation. Diode emulation function and pulse-skipping mode (PSM) are built in to improve power efficiency at light loads. The output current-sense amplifier (OCS-AMP) allows current-sense resistors as low as  $5m\Omega$  to  $15m\Omega$  for reducing power loss. Moreover the charge-pump driver adopts N-channel MOSFETs for on/off control of output power-path, instead of P-channel MOSFETs having higher cost. In operation the output bleeders at BLD and VBUS pins can be turned on to discharge output voltage (VBUS) during the VBUS negative transition, in the hard reset process, or after the removal of the USB-C connector.

The PD Safe<sup>®</sup> power delivery operation consists of overvoltage protection (OVP) at the VBUS pin, undervoltage protection at the VO pin, output CC regulation and VCONN1/2 output current-limit function. With the PD Safe<sup>®</sup> feature, trip levels of the OVP and UVP can be set dynamically for each output voltage target. The CC regulation level is also adaptively programmed according to the current level in full load.

The "CC1/2 Functions" block consists of the physical layer, three selectable levels of the pull-up current sources Ip (instead of resistors Rp), a controllable pull-down resistor Rd and programmable VCONN power-path switches.

#### Undervoltage Lockout (UVLO)

The RTQ7882-QT UVLO function continuously monitors bias voltages at the VDD and V2 pins. When both of the supply voltages (VDD and Vv2) rise above the respective rising UVLO thresholds, the internal UVLO signals will go low to activate the MCU. In addition, the IC also monitors the bias voltage at the PVDD pin for UVLO function. Only when all of the UVLO signals go low, or the PWM Buck controller will not be activated; meanwhile the MCU or PWM controllers will be kept in the "Undervoltage Lockout" state to prevent any undesirable operation.

#### Pulse-Skipping Mode (PSM) with Diode Emulation

When a switch-mode converter operates in light load condition, most power loss is caused by switching losses. To reduce switching loss in light load condition, the switching frequency needs to be reduced by entering the pulse-skipping mode (PSM) and the discontinuous conduction mode (DCM). In this operation, an internal compensation voltage VCOMP is compared by a PSM comparator, which has a programmable PSM threshold.

When the internal compensation voltage VCOMP is above the PSM threshold, the converter works in normal fixed-frequency PWM mode. As long as the VCOMP drops below the PSM threshold, the converter will enter the pulse-skipping mode to reduce switching frequency and thus diminish switching losses. The PSM threshold also defines the minimum inductor peak



current in PSM operation. Setting a larger PSM threshold will give a higher minimum peak current which in turn gives a lower switching frequency at light load for better light load efficiency at the cost of increased output voltage ripple. Conversely, a lower PSM threshold gives lower peak current and lower PSM ripple at the cost of worse light load efficiency.

A Diode Emulation Mode (DEM) is also a necessary function to avoid delivering energy from converter output to converter input during dynamic output voltage control. The DEM function is equipped with two zero-current detection (ZCD) circuits for the low-side and high-side MOSFETs respectively controlled by the LGATE1 and UGATE2 pins: The Source-to-Drain voltage (VSDB, detected via PGND and PHASE1 pins) of the low-side MOSFET is compared with a zero-current threshold (VTH\_ZCDB). When the VSDB drops below the VTH\_ZCDB voltage, the RTQ7882-QT turns off the low-side MOSFET thereby avoiding reverse inductor current. In DEM operation, the behavior of the low-side MOSFET resembles a diode. The second ZCD circuit compares the Source-to-Drain voltage (VSDD, detected via PHASE2 and ZCD pins) of the high-side MOSFET with a zero-current threshold (VTH ZCDD) to achieve the DEM function.

#### Cable Voltage Drop Compensation (CDC)

In a power delivery system with both a Provider and a Consumer, the Provider with the RTQ7882-QT AnyVolt<sup>®</sup> feature can slightly adjust its CV output voltage to compensate voltage drop across the USB cable. A PD controller of the Consumer can request higher VBUS voltage from the Provider through PD communication to achieve an accurate application voltage.

There is another method to implement the CDC function without PD communication. The RTQ7882-QT can use the ADC to detect the output current-sense voltage (VCSO) between CSOP and CSON pins and adaptively add a proper output voltage offset (VCDC) to compensate the cable voltage drop. The output voltage offset (VCDC) is gradually added by adjusting the CV regulated output voltage (VREG\_VO) and is approximately proportional to the converter output current (IOUT). VCDC is approximately determined by

the following equation:

VCDC = IOUT X RCABLE

where:

RCABLE is a preset value of parasitic resistance of USB cable.

#### VBUS Overvoltage Protection (VBUS OVP)

In Figure 1, the VBUS OVP function is a hardware-based protection which monitors the voltage at the VBUS pin via a built-in resistor-divider. When the VBUS voltage exceeds its OVP threshold, the output of the OVP comparator goes high and starts the debounce time counting. At the end of the debounce time counting, the signal VBUS OVP goes high to turn off the PWM controller. The OVP trip voltage is programmable from 3.3V to 24V (8-bit, 100mV/step typ.) and its debounce time is also selectable to meet various application requirements.

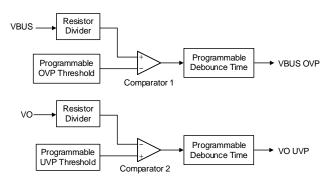


Figure 1. Functional diagram of VBUS OVP and VO UVP

#### VO Undervoltage Protection (VO UVP)

In Figure 1, the VO UVP function is a hardware-based protection which monitors the voltage at the VO pin via a built-in resistor-divider. When the VO voltage falls below its UVP threshold, the output of the UVP comparator goes high and starts the debounce time counting. At end of the debounce time, the signal VO UVP goes high to turn off PWM controller. The UVP trip voltage is programmable from 3V to 20V (8-bit, 100mV/step typ.) and its debounce time is also selectable to avoid false triggering and to meet various application requirements.

### **RTQ7882-QT**

### AnyCurrent<sup>TM</sup> Constant-Current (CC) Regulation

It is noted that a robust system is very important in USB PD operations, the AnyCurrent<sup>TM</sup> CC regulation allows setting the most suitable CC level for a negotiated PD system.

The RTQ7882-QT integrates a current-sense amplifier to sense output current for CC regulation and also through an ADC to the MCU for the output current to be recorded. The amplifier accurately sense the current-sense voltage (i.e., Vcs = output current x current-sense resistor) between the CSOP and CSON pins. The recommended current-sense voltage range for CC regulation is from 5mV to 35mV which is programmed by an internal 10-bit DAC (digital-to analog converter) with 0.0625mV/step resolution.

#### Power-Path Gate Driver for Driving N-Channel MOSFETs

The RTQ7882-QT integrates a power-path gate driver to control external output blocking MOSFETs between the output of the PWM converter and the USB-C VBUS terminal. A built-in charge pump is included to supply the gate driver to turn on the external N-channel power MOSFETs, which allow power systems to be more cost-effective, compared to the counterpart, P-channel power MOSFETs.

#### Online Firmware Update via Slave I<sup>2</sup>C or CC1/CC2 Interface

The embedded MTP memory allows the RTQ7882-QT's firmware to be updated by an EC (Embedded Controller) or AP (Application Processor) through the I<sup>2</sup>C slave interface. The RTQ7882-QT provides some firmware-programmable desian features, which greatly eases the design efforts during product development stage. End users are also allowed to update the firmware through CC1/CC2.



### Absolute Maximum Ratings (Note 1)

| • V2 to GND  | –0.3V to 2.5V              |
|--|----------------------------|
| VDD, PVDD to GND   | –0.3V to 6.5V              |
| GPIOV, GPIOI to GND  | –0.3V to 6.5V              |
| • VBUS, CSOP, CSON, VO, BLD, ZCD to GND                            | –0.3V to 25V               |
| CSOP to CSON Voltage (VCSOP-CSON)                                  | –5V to 5V                  |
| GP to GND  | –0.3V to 33V               |
| • VIN, PCIN, PCIP/CSIP, CSIN to GND (DC)                           | –0.3V to 32V               |
| (< 0.4s)   | –0.3V to 36V               |
| ZCD to CSOP (Vzcd-csop) and  |                            |
| ZCD to CSON Voltage (Vzcd-cson)                                    | –0.3V to 6.5V              |
| PCIP/CSIP to CSIN Voltage (VPCIP/CSIP-CSIN)                        | –5V to 5V                  |
| VIN to PCIP/CSIP (VVIN-PCIP/CSIP) and                              |                            |
| VIN to PCIN Voltage (VVIN-PCIN) and                                |                            |
| VIN to CSIN Voltage (Vvin-csin)                                    | –0.3V to 6.5V              |
| PCIP/CSIP to PCIN Voltage (VPCIP/CSIP-PCIN)                        | –5V to 5V                  |
| EN to GND  |                            |
| • I <sup>2</sup> C Pins (SCK1, SDA1, IRQ/ALERT, SCK2, SDA2) to GND | –0.3V to 6.5V              |
| GPIO Pins (SYN, GPIO, RT1, RT2) to GND                             | –0.3V to 6.5V              |
| DP, DM to GND  | –0.3V to 25V               |
| CC1, CC2 to GND  | –0.3V to 25V               |
| BOOT1/2 to PHASE1/2 (VBOOT-PHASE)                                  | –0.3V to 6.5V              |
| UGATE1/2 to PHASE1/2   | 0.3V to VBOOT-PHASE + 0.3V |
| PHASE1 to GND (DC)   | –0.3V to 30V               |
| (< 20ns)   | –5V to 36V                 |
| PHASE2 to GND (DC)   | –0.3V to 25V               |
| (< 20ns)   | –5V to 30V                 |
| LGATE1/2 to PGND   | –0.3V to Vpvdd + 0.3V      |
| PGND, CCGND to GND   | –0.3V to 0.3V              |
| <ul> <li>Power Dissipation, PD @ TA = 25°C</li> </ul>              |                            |
| WQFN-48L 6x6   | 3.73W                      |
| WET-WQFN-48L 6x6   | 3.67W                      |
| Package Thermal Resistance (Note 2)                                |                            |
| WQFN-48L 6x6, θJA  | 26.8°C/W                   |
| WQFN-48L 6x6, θJC  | 1.3°C/W                    |
| WET-WQFN-48L 6x6, θJA  | 27.2°C/W                   |
| WET-WQFN-48L 6x6, θJC  | 3.5°C/W                    |
| Lead Temperature (Soldering, 10 sec.)                              |                            |
| Junction Temperature   |                            |
| Storage Temperature Range  | –65°C to 150°C             |
| • ESD Susceptibility (Note 3)                                      |                            |
| HBM (Human Body Model)   | 2kV                        |

### Recommended Operating Conditions (Note 4)

| PWM Converter Input Voltage, VIN       | 4.5V to 30V       |
|--|-------------------|
| PWM Converter Output Voltage, Vour     | 3V to 22V         |
| VDD Output Voltage/PVDD Supply Voltage | 4.5V to 5.5V      |
| Junction Temperature Range             | –40°C to 125°C    |
| Ambient Temperature Range              | –40°C to 105°C    |
| Minimum MTP Memory Write/Erase Cycles  | 100cycles at 25°C |

### **Electrical Characteristics**

| Parameter   | Symbol      | Test Conditions   | Min  | Тур   | Max  | Unit |  |  |
|---|-------------|---|------|-------|------|------|--|--|
| VDD and V2 Linear Regulators (VDD LDO and V2 LDO), Undervoltage Lockout (UVLO) and Enable Control |             |   |      |       |      |      |  |  |
| VDD Output Voltage  |             | In normal mode,<br>V <sub>IN</sub> = 12V, Io = 0mA, $C_{VDD}$ = 4.7 $\mu$ F                       | 4.7  | 5     | 5.3  | - V  |  |  |
| (5.0V Normal/4.3V DGM)  | Vreg_vdd    | In deep-green mode,<br>$V_{IN} = 12V$ , Io = 0mA, $C_{VDD} = 4.7 \mu F$                           | 3.9  | 4.2   | 4.5  | V    |  |  |
| VDD Load Regulation   | VDROP_VDD12 | $\label{eq:VIN} \begin{array}{l} VIN = 12V, \ Io = 100mA, \\ CVDD = 4.7\muF \end{array}$          |      | 0.3   |      | V    |  |  |
| Drop Voltage (5.0V<br>Normal)   | Vdrop_vdd5  | $\label{eq:VIN} \begin{array}{l} VIN = 5V, \ Io = 100mA, \\ C \forall DD = 4.7 \mu F \end{array}$ |      | 0.3   |      | V    |  |  |
| VDD Short Current   | ISC_VDD     | $V_{IN} = 12V, V_{DD} = 3V$ short to GND  |      | 150   |      | mA   |  |  |
| VIN Normal Operating<br>Current   | IOP_VIN     | VIN = 12V, PWM = MCU = on,<br>digital output pins=open  |      | 10    |      | mA   |  |  |
| VIN Operating Current in<br>Deep Green-Mode (DGM)   | Idgm_vin    | V <sub>IN</sub> = 12V, PWM = off, MCU = off,<br>no load current, CC1/CC2 RX<br>detection          |      | 0.5   |      | mA   |  |  |
| VIN Operating Current in<br>Deep Green-Mode<br>(DGM_LQ)   | IDGM_LQ_VIN | VIN = 12V, PWM = MCU = off,<br>CC1/CC2 falling detection only                                     |      | 120   |      | μΑ   |  |  |
| V2 Output Voltage   | Vregv2      | In normal mode<br>Iv₂ = 20mA load, Cv₂ = 1µF  | 1.62 | 1.8   | 1.98 | V    |  |  |
| V2 Short-Circuit Current  | ISC_V2      | VIN =12V, VDD = 5V<br>V2 short to GND   |      | 50    |      | mA   |  |  |
| VDD POR Voltage<br>Threshold  |             | VDD rising  | 3.8  | 4     | 4.2  | V    |  |  |
| VDD UVLO Voltage<br>Hysteresis  |             | VDD falling   |      | 0.225 |      | V    |  |  |
| PVDD POR Threshold  |             | VPVDD rising  | 3.8  | 4     | 4.2  | V    |  |  |
| PVDD UVLO Hysteresis  |             | VPVDD falling   |      | 0.2   |      | V    |  |  |
| PVDD Input Current in<br>PWM Shut Down  |             | $V_{IN} = 12V, V_{DD} = 5V, V_{PVDD} = 5V,$<br>PVDD_EN = off, PWM = off                           |      |       | 3    | μΑ   |  |  |
| EN Internal Pull-High<br>Voltage  |             | VIN = 12V, VDD = 5V, EN open  | 3    |       | 5    | V    |  |  |



| Parameter  | Symbol        | Test Conditions   | Min  | Тур  | Max  | Unit |
|--|---------------|---|------|------|------|------|
| EN Internal Pull-High<br>Resistor  |               | VIN = 12V, VDD = 5V, EN = 0   |      | 1200 |      | kΩ   |
| EN Threshold Voltage   | VIH_EN        | VIN = 12V, VDD = 5V   | 1.5  |      | VDD  | V    |
| EN Threshold Voltage   | VIL_EN        | VIN = 12V, VDD = 5V   | 0    |      | 0.4  | V    |
| PWM Controller – Program   | mmable Oscil  | lator, Maximum On-Time,   |      |      |      |      |
| PWM Frequency Range  | fpwm          | Programmable  | 200  |      | 600  | kHz  |
| PWM Frequency Accuracy   |               | fpwm = 300kHz/400kHz  | -10  |      | 10   | %    |
| MCU Section  |               |   |      |      |      |      |
| MCU Clock Frequency  | fMCU          |   | 19.4 | 21.6 | 23.8 | MHz  |
| OSC 80K Frequency in<br>Deep Green-Mode                                      | f80K          |   |      | 80   |      | kHz  |
| PWM Controller – Consta  | nt-Voltage (C | V) Control Loop   |      |      |      | •    |
| CV Regulated Voltage<br>Range at VO Pin                                      | Vreg_vo       | Programmable (11-bit),<br>9.93mV/step   | 3    |      | 22   | V    |
| CV Regulated Voltage<br>Accuracy at VO Pin<br>(CVDAC_11bit)                  |               | Vout = 3.3V/5V/9V   | -120 |      | 120  | mV   |
| CV Regulated Voltage<br>Accuracy at VO Pin<br>(CVDAC_11bit)                  |               | Vout = 12V/15V/20V  | -200 |      | 200  | mV   |
| PWM Controller – Consta  | nt-Current (C | C) Control Loop and Output  |      |      |      |      |
| CSON and CSOP<br>Operating Voltage Range                                     |               |   | 3    |      | 22   | V    |
| CC Regulated Voltage<br>Range between CSOP<br>and CSON Pins<br>(CCDAC_10bit) | Vref_cc       | CSAgain = 40, programmable<br>(10-bit), 0.0625mV/step (typ.),<br>VCSON and VCSOP > 3V | 5    |      | 35   | mV   |
| CC Regulated Voltage<br>Accuracy between CSOP<br>and CSON Pins               |               | CSAgain = 40, nominal VREF_CC =<br>5mV/15mV/25mV                                      | -1   |      | 1    | mV   |
| CSOP/CSON Input  |               | PWM bias = on   |      |      | 50   | •    |
| Current  |               | PWM bias = off  |      |      | 1    | μΑ   |
| CSA Detection Voltage<br>Range between CSIP and<br>CSIN Pins                 |               | CSAgain = 40  | 5    |      | 35   | mV   |
| CSIP/CSIN Input Current  |               | PWM bias = on   |      |      | 50   | •    |
| in VinCSA  |               | PWM bias = off  |      |      | 1    | μΑ   |
| PWM Controller – Input C   | urrent Compa  | arison, Slope Compensation  |      |      |      |      |
| Maximum Input<br>Overcurrent (INOC)<br>Voltage Threshold Range               | VTH_CSMAX     | Programmable  | 30   |      | 150  | mV   |
| Maximum Input<br>Overcurrent (INOC)<br>Voltage Threshold<br>Accuracy         |               | VTH_CSMAX = 30mV, 120mV   | -10  |      | 10   | mV   |

## **RTQ7882-QT**

| Parameter  | Symbol             | Test Conditions  | Min       | Тур      | Max      | Unit  |
|--|--------------------|--|-----------|----------|----------|-------|
| Voltage Rate Range of Slope Compensation                       |                    | Programmable   | 0         |          | 80       | mV/μs |
| PCIP/CSIP Input Current  |                    | In PSM, VCSIP = 24V  |           |          | 50       |       |
| in INOC  |                    | PWM bias = off, VCSIP = 24V  |           |          | 3        | μA    |
|  |                    | In PSM, VCSIN = 24V  | = 24V     |          | 30       |       |
| PCIN Input Current   |                    | PWM bias = off, VCSIN = 24V  |           |          | 3        | μA    |
| PWM Controller – Zero-C  | urrent Detection   | on (ZCD)   |           |          |          | •     |
| MOS-D ZCD Voltage<br>Threshold between<br>PHASE2 and ZCD Pins  | VTH_ZCDD           | To compare the PHASE2-to-ZCD voltage                                 |           | 4        |          | mV    |
| MOS-B ZCD Voltage<br>Threshold between PGND<br>and PHASE1 Pins | VTH_ZCDB           | To compare the<br>PGND-to-PHASE1 voltage                             |           | 4        |          | mV    |
| 700 100 100 0001   | In PSM, Vzcd = 20V |  |           |          | 300      |       |
| ZCD Input Current  |                    | PWM bias = off, VzcD = 20V   |           |          | 90       | μA    |
| PWM Controller – Gate D  | rivers             |  |           |          | 1        |       |
|  |                    |  |           | 1.7      |          |       |
| UGATE1/2 Pull-High<br>Resistance                               |                    | Programmable,<br>VBOOT1/2-PHASE1/2 = 5V,<br>VBOOT1/2-UGATE1/2 = 0.1V |           | 5        |          | -     |
|  |                    |  |           | 10       |          | Ω     |
|  |                    |  |           | 20       |          |       |
| UGATE1/2 Pull-Low<br>Resistance                                |                    | VUGATE1/2 - VPHASE1/2 = 0.1V   |           | 0.8      |          | Ω     |
|  |                    |  |           | 1.7      |          |       |
| LGATE1/2 Pull-High   |                    | Programmable,  |           | 5        |          | Ω     |
| Resistance   |                    | VPVDD - VLGATE1/2 = 0.1V   |           | 10       |          |       |
|  |                    |  |           | 20       |          |       |
| LGATE1/2 Pull-Low<br>Resistance                                |                    | VLGATE1/2 = 0.1V   |           | 0.8      |          | Ω     |
| Dead-Time at LGATE1/2<br>Falling Edge                          |                    |  |           | 40       |          | ns    |
| Dead-Time after<br>UGATE1/2 Falling Edge                       |                    |  |           | 40       |          | ns    |
| System Protections – Ov  | ervoltage, Und     | lervoltage, and Overcurrent Prote                                    | ctions (C | OVP, UVF | , and OC | P)    |
| VIN UVP Voltage<br>Threshold Range                             | VTH_VINUV          | Programmable, (8-bit),<br>125mV/step (typ.)                          | 4         |          | 27       | V     |
| VIN UVP Voltage<br>Threshold Accuracy                          |                    | Setting of VTH_VINUVP =<br>5V/10V/15V                                | -5        |          | 5        | %     |
| VIN OVP Voltage<br>Threshold Range                             | VTH_VINOV          | Programmable, (8-bit),<br>125mV/step (typ.)                          | 4         |          | 30       | V     |
| VIN OVP Voltage<br>Threshold Accuracy                          |                    | Setting of VTH_VINOVP = 19V/26V                                      | -5        |          | 5        | %     |
| VBUS OVP Voltage<br>Threshold Range                            | VTH_VBUSOV         | Programmable, (8-bit),<br>100mV/step (typ.)                          | 3.3       |          | 24       | V     |



| Parameter   | Symbol        | Test Conditions                                 | Min      | Тур     | Мах     | Unit |
|---|---------------|---|----------|---------|---------|------|
| VBUS OVP Voltage<br>Threshold Accuracy                    |               | Setting of VTH_VBUSOV = 12V/20V                 | -5       |         | 5       | %    |
| VBUS OVP Voltage<br>Threshold Accuracy                    |               | Setting of VTH_VBUSOV = 3.3V/ 5V                | -0.3     |         | 0.3     | V    |
| ZCD Pin OVP Voltage<br>Threshold<br>(VO Pin Open, OVP)    | VTH_ZCDOV     |   | -7       | 125     | 7       | %    |
| VO UVP Voltage<br>Threshold Range                         | ντη_λουλ      | Programmable, (8-bit),<br>100mV/step (typ.)     | 3        |         | 20      | V    |
| VO UVP Voltage<br>Threshold Accuracy                      |               | Setting of VTH_VOUV =<br>5V/12V/20V             | -5       |         | 5       | %    |
| VO UVP Voltage<br>Threshold Accuracy                      |               | Setting of VTH_VOUV = 3V                        | -0.2     |         | 0.2     | V    |
| USB PD Controller – CC1                                   | /2 Voltage De | tections, BMC Transmitter/Receive               | er and V | CONN Sv | vitches |      |
| CC1/2 Pull-Up Current<br>Source – 1                       | lp1           | For default USB power                           | 64       | 80      | 96      | μΑ   |
| CC1/2 Pull-Up Current<br>Source – 2                       | lp2           | For 1.5A and 5V                                 | 165.6    | 180     | 194.4   | μA   |
| CC1/2 Pull-Up Current<br>Source – 3                       | lp3           | For 3A and 5V                                   | 303.6    | 330     | 356.4   | μA   |
| CC1/2 Open-Loop<br>Clamping Voltage for<br>pull-up Source | VCC_CLAMP     | V <sub>DD</sub> = 5V @ pull-up Current<br>330μA | 2.9      | 3.25    |         | V    |
| CC1/2 Pull-Down Resistor                                  | Rd            | $V_{DD} = 5V @ pull-up 56k\Omega$               | 4.6      | 5.1     | 5.6     | kΩ   |
| Transmitter High-Level<br>Output Voltage Range            |               |   | 1.05     | 1.125   | 1.2     | V    |
| Transmitter Low-Level<br>Output Voltage Range             |               |   | 0        | -       | 75      | mV   |
| Rising Time of the<br>Transmitter Output<br>Voltage       |               | From 10% to 90%,<br>CL=200pF to 600pF           | 300      |         |         | ns   |
| Falling Time of the<br>Transmitter Output<br>Voltage      |               | From 90% to 10%,<br>CL= 200pF to 600pF          | 300      |         |         | ns   |
|   |               |   |          | 0.8     |         |      |
| Receiver High-Level Input                                 |               |   |          | 0.7     |         | V    |
| Voltage Range   |               |   |          | 0.6     |         | v    |
|   |               |   |          | 0.5     |         |      |
|   |               |   |          | 0.5     |         |      |
| Receiver Low-Level Input                                  |               |   |          | 0.4     |         | v    |
| Voltage Range   |               |   |          | 0.3     |         |      |
|   |               |   |          | 0.2     |         |      |
| VCONN On-Resistance of<br>VDD-to-CC1/2 MOSFET             |               | VDD = 5V, output current = 20mA                 |          | 10      | 15      | Ω    |



| Parameter   | Symbol        | Test Conditions                 | Min | Тур  | Max | Unit                                  |
|---|---------------|---------------------------------|-----|------|-----|---------------------------------------|
| VCONN Output Voltage<br>Drop VDD-to-CC1/2<br>MOSFET |               | VDD = 5V, output current = 20mA |     | 0.2  | 0.3 | V                                     |
| VCONN Current-Limit<br>Threshold                    |               | CC1/CC2 = GND                   |     | 50   |     | mA                                    |
| CC1/CC2 Short to VBUS<br>Protection                 |               |                                 | 5.7 | 6    | 6.3 | V                                     |
| DPDM Interfaces in Source                           | e Role Operat | ion                             |     |      |     |                                       |
| On-Resistance of<br>DP-to-DM MOSFET                 |               |                                 |     |      | 40  | Ω                                     |
| DP/DM High-Level Output                             | Voh_dpdm      | Sourcing ourront - 2mA          |     | 3.3  |     | V                                     |
| Voltage   | VOH_DPDM      | Sourcing current = 2mA          |     | 1.8  |     | V                                     |
| DP/DM Low-Level Output<br>Voltage                   | Vol_dpdm      | Sinking current = 2mA           |     |      | 0.3 | V                                     |
|   |               |                                 |     | 0.3  |     |                                       |
| DP/DM Voltage Falling<br>Threshold for Plug-Out     |               |                                 |     | 0.4  |     | V                                     |
| Detection   | VREF1_DPDM    |                                 |     | 0.5  |     | v                                     |
|   |               |                                 |     | 0.6  |     |                                       |
| Input Voltage Offset<br>Selection                   | VIN_LEV       |                                 |     | 0    |     | V                                     |
| VREF2H_DPDM,<br>VREF2L_DPDM                         |               |                                 |     | 0.4  |     | , , , , , , , , , , , , , , , , , , , |
|   |               | VIN_LEV = 0V                    |     | 0.8  |     |                                       |
|   |               |                                 |     | 1.3  |     |                                       |
|   |               |                                 |     | 1.9  |     |                                       |
| RX Upper Input Voltage                              | Vref2h_dpdm   |                                 |     | 2.05 |     |                                       |
| Threshold   |               |                                 |     | 1.2  |     |                                       |
|   |               | VIN_LEV = 0.4V                  |     | 1.7  |     |                                       |
|   |               |                                 |     | 2.3  |     |                                       |
|   |               |                                 |     | 2.45 |     |                                       |
|   |               |                                 |     | 0.6  |     | - V                                   |
|   |               | VIN_LEV = 0V                    |     | 1.1  |     |                                       |
|   |               |                                 |     | 1.8  |     |                                       |
| RX Lower Input Voltage                              | Vref2l_dpdm   |                                 |     | 1.95 |     |                                       |
| Threshold   | VREFZL_DPDIVI |                                 |     | 1    |     |                                       |
|   |               | $\lambda$                       |     | 1.5  |     |                                       |
|   |               | $VIN_{LEV} = 0.4V$              |     | 2.2  |     |                                       |
|   |               |                                 |     | 2.35 |     |                                       |
| DP/DM Internal Pull-Low<br>Resistance               | RDWN_DPDM     |                                 | 16  | 20   | 24  | kΩ                                    |



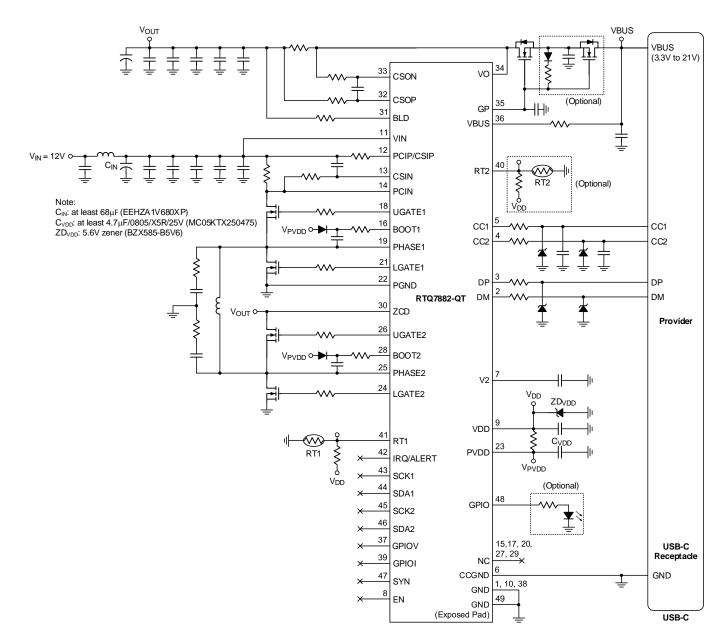
| Parameter  | Symbol         | Test Conditions  | Min                     | Тур           | Max                      | Unit |
|--|----------------|--|-------------------------|---------------|--------------------------|------|
|  |                |  | 1.13                    | 1.2           | 1.27                     |      |
| DP/DM Output Voltage for                                   |                |  | 1.88                    | 2             | 2.12                     |      |
| Divider Mode   |                |  | 2.57                    | 2.7           | 2.84                     | V    |
|  |                |  | 3.14                    | 3.3           | 3.47                     |      |
| Output Resistance DP/DM<br>for Divider Mode<br>2.0/2.7/3.3 |                |  |                         | 30            |                          | kΩ   |
| Output Resistance DP/DM for Divider Mode 1.2               |                |  |                         | 100           |                          | kΩ   |
| DP/DM Output Voltage-1<br>for SRC                          | VSRC1_DPDM     |  |                         | 0.6           |                          | V    |
| DP/DM Output Voltage-2<br>for SRC                          | VSRC2_DPDM     |  |                         | 3.3           |                          | V    |
| DP/DM Short to VBUS<br>Protection                          |                |  | 5.415                   | 5.7           | 5.985                    | V    |
| Charge-Pump Gate Driver                                    | rs and Bleeder | ΓS   |                         |               |                          |      |
| GP On-Resistance of<br>Pull-Low MOSFET                     |                | Pull-low NMOS is on, sinking IGP<br>= 10mA, VDD = 5V                           |                         |               | 200                      | Ω    |
| Maximum GP Voltage   |                | $V_{VO}$ = 20V, R <sub>GP-to-GND</sub> = 667k $\Omega$                         | V <sub>VO</sub> +<br>4V | Vvo +<br>4.5V | V <sub>VO</sub> +<br>10V | V    |
| BLD On-Resistance of<br>Pull-Low MOSFET                    |                | Pull-low NMOS is on, sinking IBLD<br>= 10mA, VDD = 5V                          |                         | 20            | 40                       | Ω    |
| BLD Leakage Current  |                | $V_{BLD} = 20V$ , pull-low NMOS is off $V_{DD} = 5V$                           |                         |               | 1                        | μA   |
| VBUS Bleeder Resistor                                      |                | Pull-low NMOS is on<br>VDD = 5.0V & VBUS = 23V                                 |                         | 1.2           |                          | kΩ   |
|  |                | /ALERT, SCK1, SDA1, SCK2 and \$<br>\1, SCK2, SDA2, GPIOV, GPIOI, S\            |                         | ), RT1 an     | d RT2)                   |      |
| I <sup>2</sup> C/GPIO High-Level Input<br>Voltage Range    | Viн            | For the pins configured as input pins  | 1.5                     |               |                          | V    |
| I <sup>2</sup> C/GPIO Low-Level Input<br>Voltage Range     | VIL            | For the pins configured as input pins  |                         |               | 0.4                      | V    |
| I <sup>2</sup> C/GPIO High-Level<br>Output Voltage         | Vон            | Sourcing current = 2mA, for the<br>pins configured as push-pull<br>output pins | VDD<br>- 1.5V           | VDD<br>- 0.8V |                          | V    |
| I <sup>2</sup> C/GPIO Low-Level<br>Output Voltage          | Vol            | Sinking current = 2mA  |                         |               | 0.3                      | V    |
| I <sup>2</sup> C/GPIO Leakage<br>Current                   |                | Pin input voltage = 5V   |                         |               | 1                        | μA   |
| RT1/2 Current Source                                       |                | V <sub>RT1/2</sub> < 2.7V  | 92                      | 100           | 108                      | μΑ   |

**Note 1.** Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions may affect device reliability.

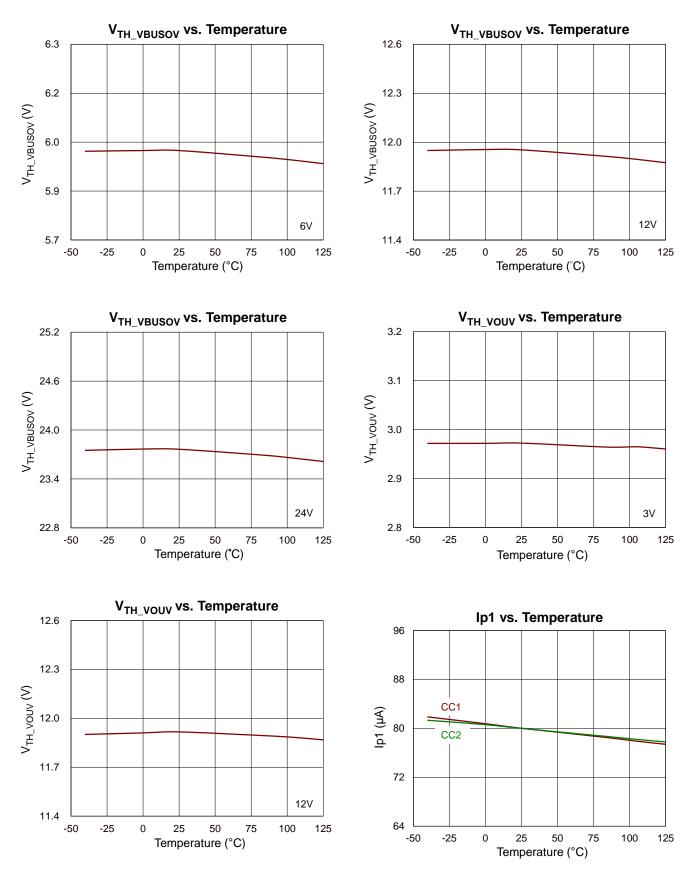
- Note 2.  $\theta_{JA}$  is measured under natural convection (still air) at  $T_A = 25^{\circ}C$  with the component mounted on a high effective-thermal-conductivity four-layer test board on a JEDEC 51-7 thermal measurement standard.  $\theta_{JC}$  is measured at the exposed pad of the package.
- Note 3. Devices are ESD sensitive. Handling precautions are recommended.
- Note 4. The device is not guaranteed to function outside its operating conditions.



### **Typical Application Circuit**

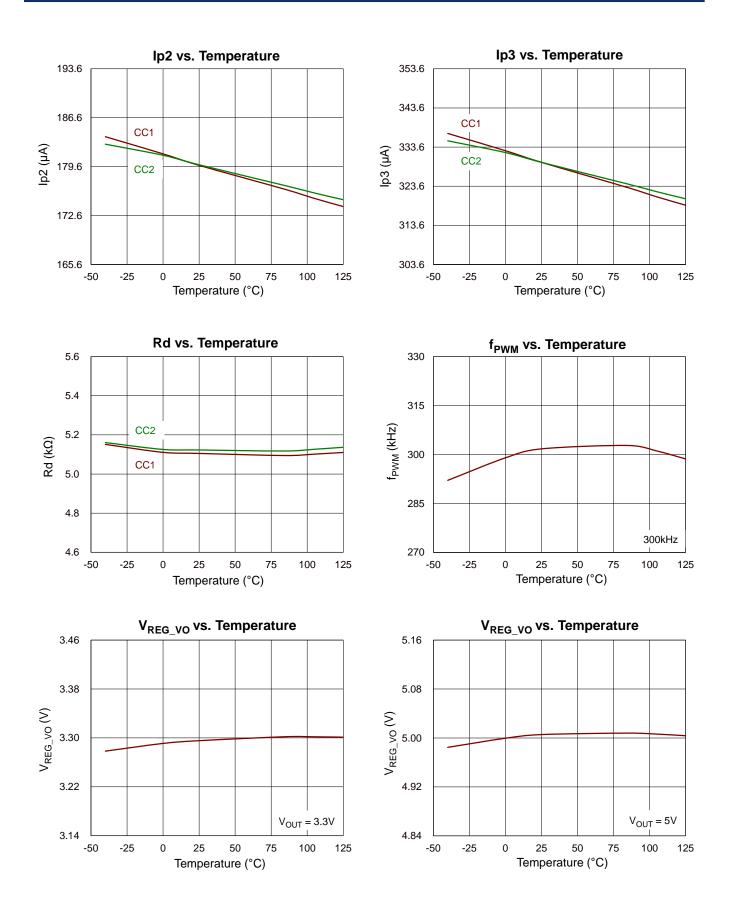


### **Typical Operating Characteristics**

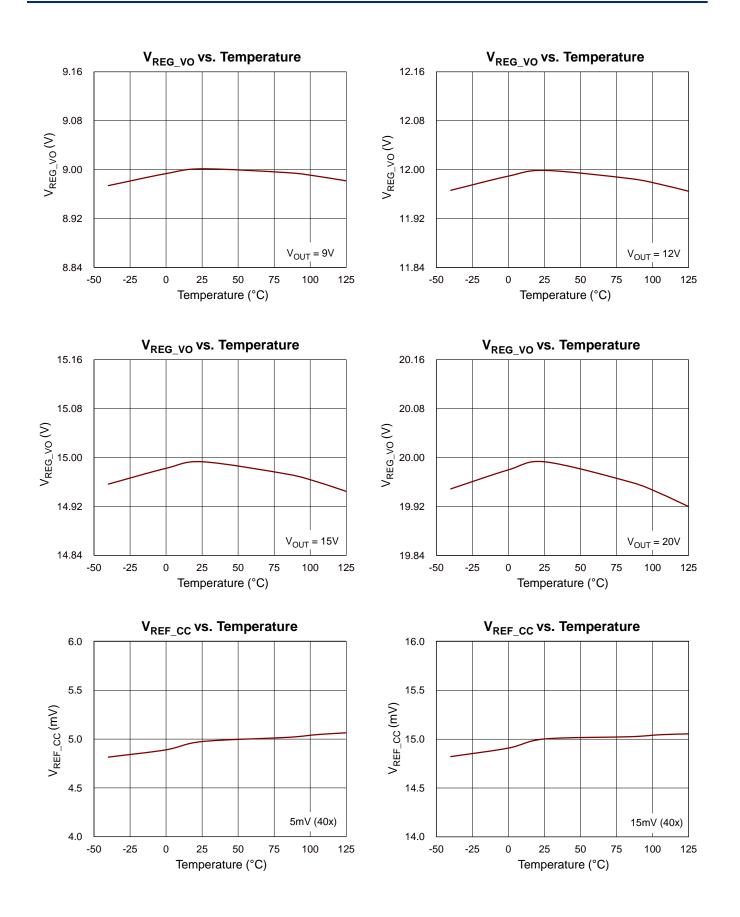


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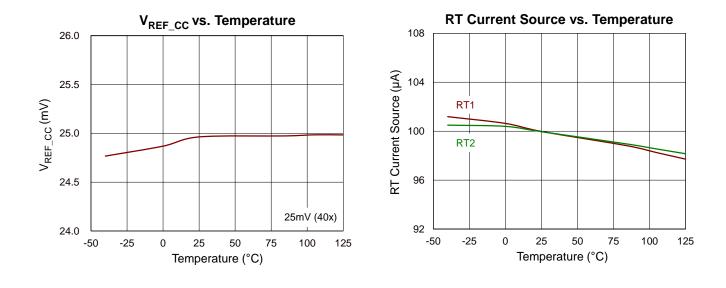


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### **Application Information**

Richtek's component specification does not include the following information in the Application Information section. Thereby no warranty is given regarding its validity and accuracy. Customers should take responsibility to verify their own designs and reserve suitable design margin to ensure the functional suitability of their components and systems.

#### **Calculating Output Discharge Time**

Figure 2 shows the functional block diagram of two built-in output bleeders at VBUS and BLD pins. The VBUS bleeder consists of an internal resistor  $(1.2k\Omega$  typ.) and a pull-low MOSFET (QBLD2) for discharging the capacitors at VBUS side; the BLD bleeder consists of an external resistor (RBLD\_EXT) and a pull-low MOSFET (QBLD1) for discharging the capacitors at the output of the PWM converter. If the blocking MOSFETs (Q1A and Q1B) are on during discharging, the BLD bleeder with larger current capability dominates the discharge time. If the blocking MOSFETs are off, the discharge time (tDIS\_CVBUS) of the capacitor connected to the VBUS pin is determined by the following equation:

$$t_{\text{DIS}\_\text{CVBUS}} = R_{\text{BLD}\_\text{INT}} \times C_{\text{VBUS}} \times \text{In}\left(\frac{V_{\text{BUS}\_\text{INI}}}{V_{\text{BUS}\_\text{FINAL}}}\right)$$

where:

- R<sub>BLD\_INT</sub> is total internal resistance during on-state of the internal MOSFET Q<sub>BLD2</sub>.
- ► C<sub>VBUS</sub> is the total capacitance, coupled to the VBUS pin.
- ► V<sub>BUS\_INI</sub> is the initial bus voltage before the discharging.
- V<sub>BUS\_FINAL</sub> is the final bus voltage at end of the discharging.

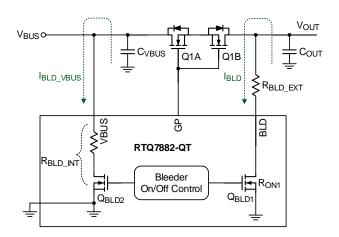


Figure 2. Functional Diagram of the Output Bleeders

Similar to the operation of the VBUS bleeder, the discharge time (t<sub>DIS\_COUT</sub>) of the capacitor connected to the output of the PWM converter is determined by the following equation:

 $t_{\text{DIS}\_\text{COUT}} = \left( R_{\text{BLD}\_\text{EXT}} + R_{\text{ON1}} \right) \times C_{\text{OUT}} \times \ln \left( \frac{V_{\text{OUT}\_\text{INI}}}{V_{\text{OUT}\_\text{FINAL}}} \right)$ 

where:

- ► RBLD\_EXT is resistance of the external resistor.
- ► RON1 is on-resistance of the internal MOSFET QBLD1.
- ► COUT is the total capacitance connected to the output of the PWM converter.
- VOUT\_INI is the initial voltage of the PWM converter output before discharging.
- ► VOUT\_FINAL is the final voltage of the PWM converter output at end of discharging.

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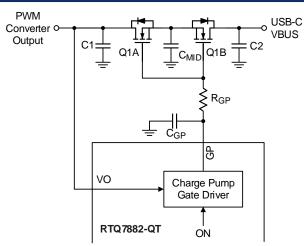


Figure 3. Functional Diagram of the Power-Path

#### Control

#### Using Charge-Pump Gate Driver for Power-Path

#### **On/Off Control**

Figure 3 shows the application schematic of a power-path on/off control. In this schematic, two N-channel MOSFETs of low on-resistance driven by a built-in gate driver, supplied by the charge pump, are employed to turn on or off the power-path between the PWM converter output and the USB-C VBUS terminal. If the internal control signal "ON" goes high, the GP voltage (V<sub>GP</sub>) will be pulled high to turn on the power MOSFETs (Q1A and Q1B) and connect the power-path. If "ON" goes low, V<sub>GP</sub> will be pulled low by a built-in MOSFET to disconnect the power-path.

Power input (VO) is needed for the charge pump, and the VO pin must be connected the PWM converter output to ensure the power MOSFETs can be turned on successfully.

An optional MLCC capacitor (CGP) can be used to reduce the VGP rising rate and surge current in the power-path as the power MOSFETs being switched on. When the power MOSFETs being switched off, the parasitic inductor and capacitors, C1 or C2, on the power path may cause voltage ringing at the drain of the Q1A or Q1B. An optional gate resistor (RGP) can be added to reduce the falling rate of the power-path current and prevent voltage spikes. A  $1\mu$ F MLCC capacitor (CMID) between the source terminals to ground is necessary in order to prevent oscillation due to such dual-MOSFET connection.

#### Thermal Considerations

The junction temperature should never exceed the absolute maximum junction temperature  $T_{J(MAX)}$ , listed under Absolute Maximum Ratings, to avoid permanent damage to the device. The maximum allowable power dissipation depends on the thermal resistance of the IC package, the PCB layout, the rate of surrounding airflow, and the difference between the junction and ambient temperatures. The maximum power dissipation can be calculated using the following formula:

#### $\mathsf{PD}(\mathsf{MAX}) = (\mathsf{TJ}(\mathsf{MAX}) - \mathsf{TA}) / \theta \mathsf{JA}$

where  $T_{J(MAX)}$  is the maximum junction temperature, TA is the ambient temperature, and  $\theta_{JA}$  is the junction-to-ambient thermal resistance.

For continuous operation, the maximum operating junction temperature indicated under Recommended Operating Conditions is 125°C. The junction-toambient thermal resistance,  $\theta_{JA}$ , is highly package dependent. For a WQFN-48L 6x6 package, the thermal resistance,  $\theta_{JA}$ , is 26.8°C/W on a standard JEDEC 51-7 high effective-thermal-conductivity four-layer test board. For a WET-WQFN-48L 6x6 package, the thermal resistance,  $\theta_{JA}$ , is 27.2°C/W on a standard JEDEC 51-7 high effective-thermal-conductivity fourlayer test board. The maximum power dissipation at T<sub>A</sub> = 25°C can be calculated as below:

 $P_{D(MAX)} = (125^{\circ}C - 25^{\circ}C) / (26.8^{\circ}C/W) = 3.73W$  for a WQFN-48L 6x6 package.

 $P_{D(MAX)} = (125^{\circ}C - 25^{\circ}C) / (27.2^{\circ}C/W) = 3.67W$  for a WET-WQFN-48L 6x6 package.

The maximum power dissipation depends on the operating ambient temperature for the fixed  $T_{J(MAX)}$  and the thermal resistance,  $\theta_{JA}$ . The derating curves in Figure 4 allows the designer to see the effect of rising ambient temperature on the maximum power dissipation.

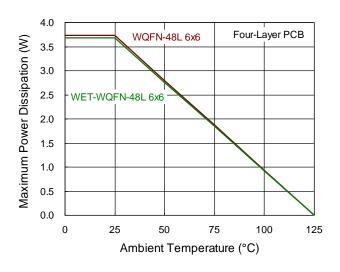


Figure 4. Derating Curve of Maximum Power Dissipation

#### Layout Considerations

- Connect the IC GND pin and the exposed pad to a ground plane (IC-ground), and then connect the IC-ground to the USB GND terminals via a low-impedance path. The exposed pad is also used to dissipate the heat into PCB.
- Connect the decoupling MLCCs near the pins of VDD, V2, PVDD and VBUS. Connect the MLCCs to the pins and IC-ground via low impedance paths.
- Connect the decoupling MLCC from the BOOT1/2 pin to the PHASE1/2 pin via a short and low-impedance path.
- Connect the PGND and PHASE1 pins respectively to the Source and the Drain of low-side power MOSFET (controlled by LGATE1) via dedicated and low-impedance paths.
- Connect the PHASE2 and ZCD pins respectively to the Source and the Drain of high-side power MOSFET (controlled by UGATE2) via a dedicated and low-impedance paths.
- Connect the GNDCC pin to GND terminals of the USB Type-C connector via dedicated and low-impedance path.

Connect the capacitor (between the CSOP and CSON pins) close to these pins. The paths of CSOP and CSON must be directly connected to the terminals of current-sense resistor (Rcso) using Kelvin connections as shown in the layout shown in Figure 5.

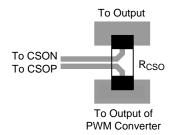


Figure 5. Kelvin Connections for the Rcso

Figure 6 is a recommended placement of the PWM Buck power-stage. A critical loop "from CIN1 → RCSI → QA → QB to CIN1" and "from Co1 → QD → QC to Co1" must be as short as possible to minimize the switching noise at CSIP/VIN, CSIN, PHASE1, PHASE2 and ZCD pins. The shorter paths also help to reduce radiated EMI. It is necessary to use an MLCC (10µF/50V, X5R/X7R) for the input capacitor (CIN1) and output capacitor (Co1). For reducing the input and output voltage ripples during heavy load operation, it is recommended to add more MLCCs or solid input and output capacitors. Moreover, to improve heat dissipation, one needs to increase the PCB areas for Drains of high-side and low-side MOSFETs.

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## **RTQ7882-QT**

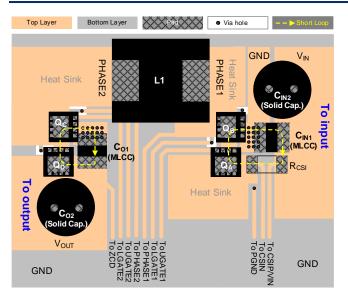
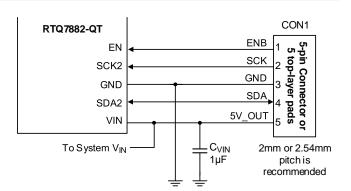


Figure 6. Recommended PCB Layout of the Power Stage

- To prevent the switching noises, separate the following signals from the switching nodes and the switching-current paths connected with PHASE pin:
  - Input and output current-sense signals
  - CC1 and CC2 signals
  - CV-loop feedback signal
- For improving ESD immunity, connect MLCCs close to the GND and VBUS terminals of the USB Type-C connector. Connect the capacitors to the USB VBUS and GND terminals through the low-impedance paths.



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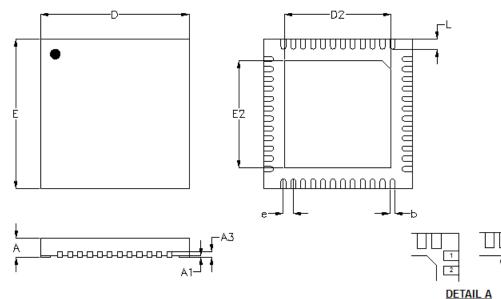
Figure 7. Connections for Manual Firmware Updates

#### Manual Firmware Update

During product development stage, users might need to download or update the RTQ7882-QT firmware. This can be done by adding a 5-pin connector (CON1) or five test pads on PCBs for updating the RTQ7882-QT firmware manually as shown in Figure 7. This connector is then connected to a "Firmware update fixture" by a 5-pin cable. The fixture is also connected to a PC via a Micro USB cable and acts as a bridge between the RTQ7882-QT and the PC. With this setup, users can download firmware to the RTQ7882-QT by using the RTQ7882-QT graphic user interface (GUI) installed in the PC. During the firmware update process, the fixture can supply current (up to 40mA) to the RTQ7882-QT and the system V<sub>IN</sub> via the 5V\_OUT pin of the 5-pin cable.

If the power from the fixture is enough to power the RTQ7882-QT and the system  $V_{IN}$ , it is not necessary to use the auxiliary input voltage for the system  $V_{IN}$ . On the other hand, if the system  $V_{IN}$  consumes more current than the fixture capability, one needs to use an auxiliary input voltage.

### **Outline Dimension**



Pin #1 ID and Tie Bar Mark Options

2

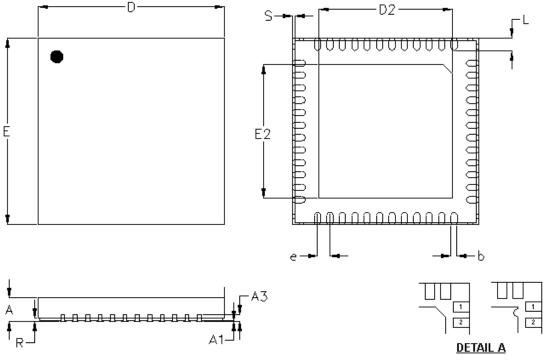
Note : The configuration of the Pin #1 identifier is optional, but must be located within the zone indicated.

| Symbol |          | Dimensions I | <b>Dimensions In Millimeters</b> |       | s In Inches |
|--------|----------|--------------|----------------------------------|-------|-------------|
|        |          | Min          | Max                              | Min   | Max         |
|        | А        | 0.700        | 0.800                            | 0.028 | 0.031       |
|        | A1       | 0.000        | 0.050                            | 0.000 | 0.002       |
|        | A3       | 0.175        | 0.250                            | 0.007 | 0.010       |
|        | b        | 0.150        | 0.250                            | 0.006 | 0.010       |
|        | D        | 5.950        | 6.050                            | 0.234 | 0.238       |
|        | Option 1 | 4.250        | 4.350                            | 0.167 | 0.171       |
| DO     | Option 2 | 4.350        | 4.450                            | 0.171 | 0.175       |
| D2     | Option 3 | 4.650        | 4.750                            | 0.183 | 0.187       |
|        | Option 4 | 4.450        | 4.550                            | 0.175 | 0.179       |
|        | E        | 5.950        | 6.050                            | 0.234 | 0.238       |
|        | Option 1 | 4.250        | 4.350                            | 0.167 | 0.171       |
| E2     | Option 2 | 4.350        | 4.450                            | 0.171 | 0.175       |
| E2     | Option 3 | 4.650        | 4.750                            | 0.183 | 0.187       |
|        | Option 4 | 4.450        | 4.550                            | 0.175 | 0.179       |
| е      |          | 0.4          | 100                              | 0.0   | 016         |
|        | L        | 0.350        | 0.450                            | 0.014 | 0.018       |
|        |          |              |                                  |       |             |

#### W-Type 48L QFN 6x6 Package

Note: The package of RTQ7882-QT uses Option 1.





Pin #1 ID and Tie Bar Mark Options

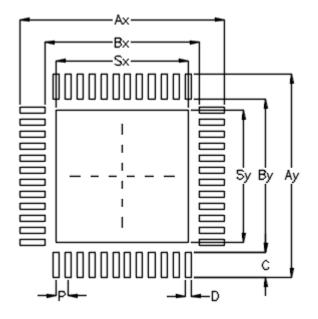
Note : The configuration of the Pin #1 identifier is optional, but must be located within the zone indicated.

| Cumbal | Dimensions I | n Millimeters | Dimension | s In Inches |  |
|--------|--------------|---------------|-----------|-------------|--|
| Symbol | Min          | Max           | Min       | Max         |  |
| А      | 0.700        | 0.800         | 0.028     | 0.031       |  |
| A1     | 0.000        | 0.050         | 0.000     | 0.002       |  |
| A3     | 0.175        | 0.250         | 0.007     | 0.010       |  |
| b      | 0.150        | 0.250         | 0.006     | 0.010       |  |
| D      | 5.950        | 6.050         | 0.234     | 0.238       |  |
| D2     | 4.250        | 4.350         | 0.167     | 0.171       |  |
| E      | 5.950        | 6.050         | 0.234     | 0.238       |  |
| E2     | 4.250        | 4.350         | 0.167     | 0.171       |  |
| е      | 0.4          | 00            | 0.0       | )16         |  |
| L      | 0.350        | 0.450         | 0.014     | 0.018       |  |
| R      | 0.050        | 0.150         | 0.002     | 0.006       |  |
| S      | 0.001        | 0.090         | 0.000     | 0.004       |  |

WET W-Type 48L QFN 6x6 Package



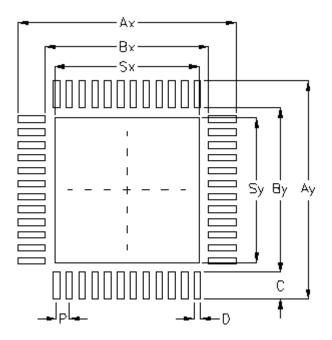
### **Footprint Information**



| Deckere          | Package |  | Footprint Dimension (mm) |      |           |      |         |      |      |      | Toloropoo |           |
|------------------|---------|--|--------------------------|------|-----------|------|---------|------|------|------|-----------|-----------|
| Раскаде          |         |  | Р                        | Ax   | Ay        | Bx   | Ву      | С    | D    | Sx   | Sy        | Tolerance |
|                  | Option1 |  |                          |      |           |      |         |      |      | 4.40 | 4.40      |           |
|                  | Option2 |  | 0.40                     | 6 90 | 6 90      | E 10 | E 10    | 0.05 | 0.20 | 4.50 | 4.50      | · 0.0E    |
| V/W/U/XQFN6x6-48 | Option3 |  | 0.40                     | 6.80 | 6.80 5.10 | 5.10 | 10 5.10 | 0.85 | 0.20 | 4.70 | 4.70      | ±0.05     |
|                  | Option4 |  |                          |      |           |      |         |      |      | 4.60 | 4.60      |           |

Note: The package of RTQ7882-QT uses Option 1.



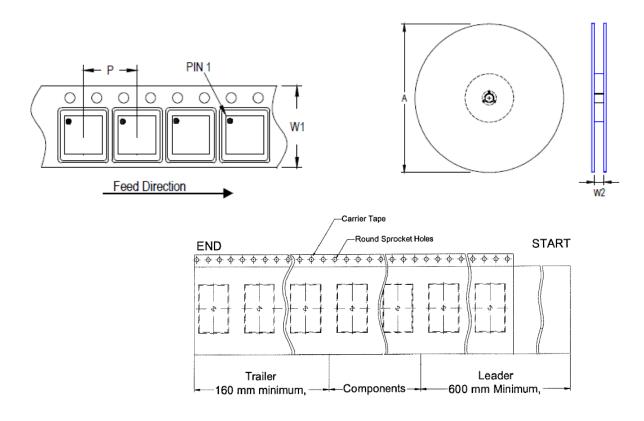


| Dookogo              | Number of |      |      | Fo   | otprint | Dimens | sion (m | m)   |      |      | Tolerance |
|----------------------|-----------|------|------|------|---------|--------|---------|------|------|------|-----------|
| Package              | Pin       | Р    | Ax   | Ay   | Bx      | Ву     | С       | D    | Sx   | Sy   |           |
| WET-V/W/U/XQFN6x6-48 | 48        | 0.40 | 6.80 | 6.80 | 5.10    | 5.10   | 0.85    | 0.20 | 4.40 | 4.40 | ±0.05     |

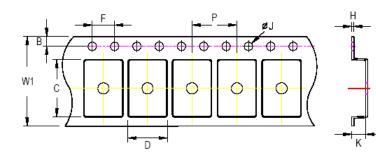


### **Packing Information**

#### Tape and Reel Data



| De alva a Tranc | Tape Size | Pocket Pitch | Reel Si | ze (A) | Units    | Trailer | Leader | Reel Width (W2) |  |
|-----------------|-----------|--------------|---------|--------|----------|---------|--------|-----------------|--|
| Package Type    | (W1) (mm) | (P) (mm)     | (mm)    | (in)   | per Reel | (mm)    | (mm)   | Min./Max. (mm)  |  |
| QFN/DFN 6x6     | 16        | 12           | 330     | 13     | 2,500    | 160     | 600    | 16.4/18.4       |  |



C, D and K are determined by component size. The clearance between the components and the cavity is as follows:

- For 16mm carrier tape: 1.0mm max.

| Tape Size | W1     | F      | C      | E      | 3      | F     |       | ØJ    |       | Н     |
|-----------|--------|--------|--------|--------|--------|-------|-------|-------|-------|-------|
| Tape Size | Max.   | Min.   | Max.   | Min.   | Max.   | Min.  | Max.  | Min.  | Max.  | Max.  |
| 16mm      | 16.3mm | 11.9mm | 12.1mm | 1.65mm | 1.85mm | 3.9mm | 4.1mm | 1.5mm | 1.6mm | 0.6mm |



#### **Tape and Reel Packing**

| Step | Photo/Description                      | Step | Photo/Description                 |
|------|--|------|-----------------------------------|
| 1    | Reel 13"                               | 4    | 1 reel per inner box <b>Box G</b> |
| 2    | HIC & Desiccant (2 Unit) inside        | 5    | 6 inner boxes per outer box       |
| 3    | Caution label is on backside of Al bag | 6    | Outer box Carton A                |

| Container       | R    | eel   |       | Box        |       |       | Carton   |       |        |  |
|-----------------|------|-------|-------|------------|-------|-------|----------|-------|--------|--|
| Package         | Size | Units | Item  | Weight(kg) | Reels | Units | Item     | Boxes | Units  |  |
| QFN and DFN 6x6 | 13"  | 2,500 | Box G | 1.11       | 1     | 2,500 | Carton A | 6     | 15,000 |  |





#### Packing Material Anti-ESD Property

| Surface<br>Resistance | Aluminum Bag                        | Reel                                | Cover tape                          | Carrier tape                        | Tube                                | Protection Band                     |
|-----------------------|-------------------------------------|-------------------------------------|-------------------------------------|-------------------------------------|-------------------------------------|-------------------------------------|
| $\Omega/cm^2$         | 10 <sup>4</sup> to 10 <sup>11</sup> |

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DSQ7882-QT-00 June 2023



#### **Datasheet Revision History**

| Version | Date      | Description | Item  |
|---------|-----------|-------------|---|
| 00      | 2023/6/19 | Final       | Ordering Information P1<br>Functional Pin Description on P4<br>Application Information on P23<br>Outline Dimension on P27<br>Footprint Information on P29 |